

Features

- ESD Protected Up To 2KV(HBM)
- High Speed Switching
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Dual P-Channel MOSFET

Maximum Ratings

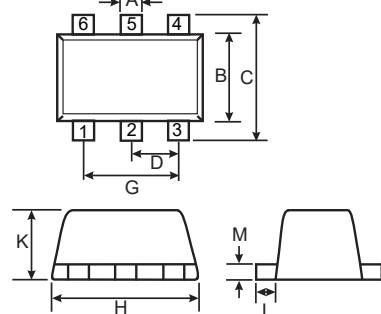
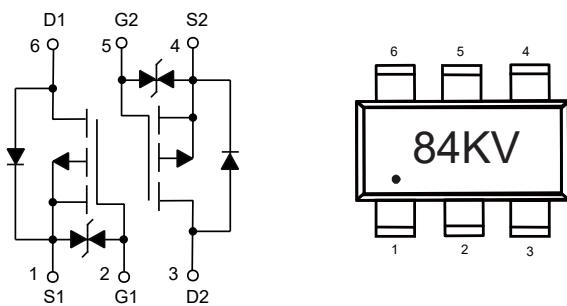
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 340°C/W Junction to Ambient^(Note 2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	-0.26	A
T _A =100°C	-0.16		
Pulsed Drain Current ^(Note 3)	I _{DM}	-1.04	A
Power Dissipation ^(Note 4)	P _D	0.37	W

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.006	0.011	0.15	0.30	
B	0.043	0.051	1.10	1.30	
C	0.059	0.067	1.50	1.70	
D	0.020		0.50		TYP.
G	0.035	0.043	0.90	1.10	
H	0.059	0.067	1.50	1.70	
K	0.022	0.026	0.55	0.65	
L	0.004	0.011	0.10	0.30	
M	0.004	0.007	0.10	0.18	

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-60			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±10	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V			-1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.6	-2.5	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-0.2A		2.2	2.9	Ω
		V _{GS} =-4.5V, I _D =-0.1A		2.5	3.5	
Forward Transconductance	g _{FS}	V _{DS} =5V, I _D =0.5A		568		mS
Gate Resistance	R _g	f=1 MHz, Open drain		1260		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				-0.26	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-0.2A			-1.3	V
Reverse Recovery Time	t _{rr}	I _F =-0.2A, dI _F /dt=100A/μs		12.4		ns
Reverse Recovery Charge	Q _{rr}			4.9		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =-25V, V _{GS} =0V, f=1MHz		33.5		pF
Output Capacitance	C _{oss}			4.2		
Reverse Transfer Capacitance	C _{rss}			2.6		
Total Gate Charge	Q _g	V _{DS} =-30V, V _{GS} =-10V, I _D =-0.2A		2.1		nC
Gate-Source Charge	Q _{gs}			0.3		
Gate-Drain Charge	Q _{gd}			0.4		
Turn-On Delay Time	t _{d(on)}	V _{DD} =-10V, V _{GS} =-10V, R _G =6Ω, I _D =-0.2A		7.3		ns
Turn-On Rise Time	t _r			3.4		
Turn-Off Delay Time	t _{d(off)}			34.5		
Turn-Off Fall Time	t _f			14.6		

Curve Characteristics

Fig.1 - Typical Output Characteristics

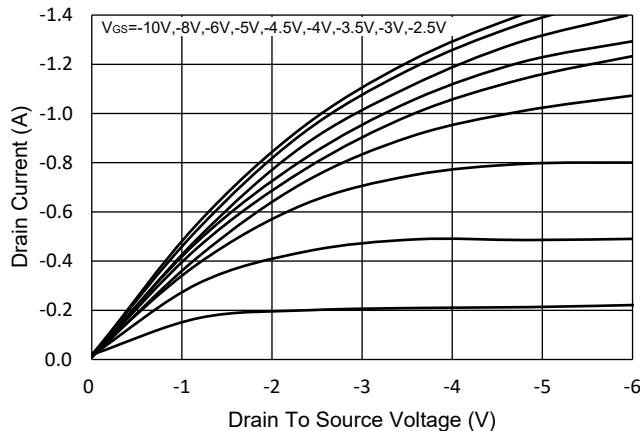


Fig.2 - Transfer Characteristic

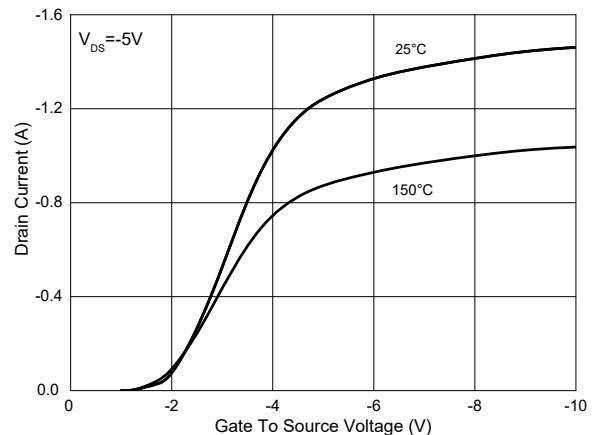


Fig.3 - $R_{DS(ON)}$ - V_{GS}

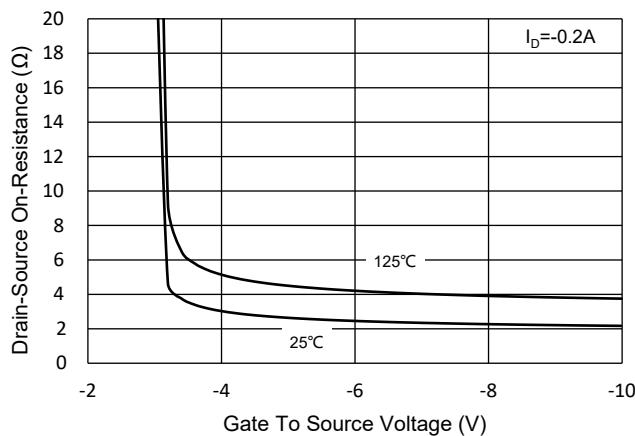


Fig.4 - $R_{DS(ON)}$ - I_D

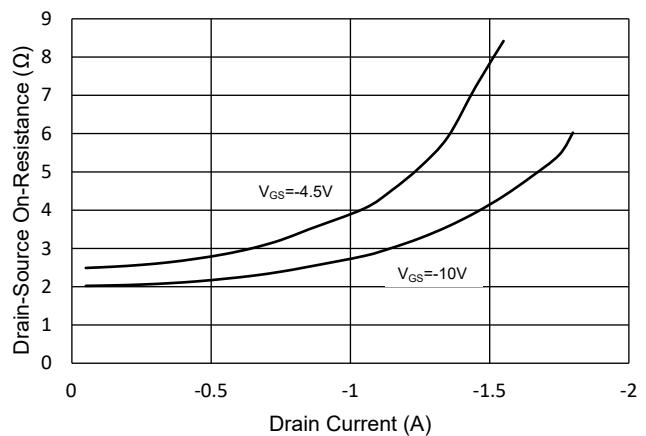


Fig.5 - Capacitance Characteristics

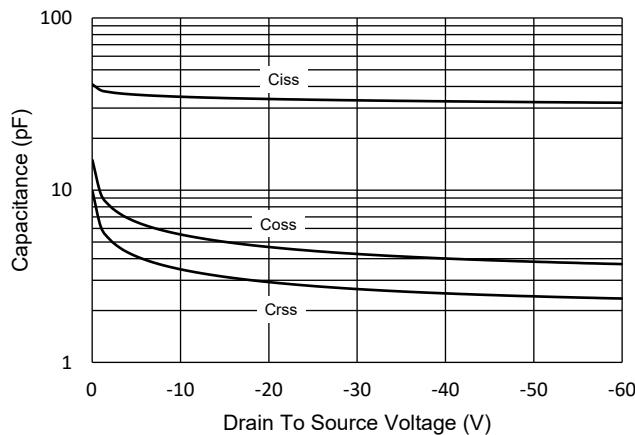
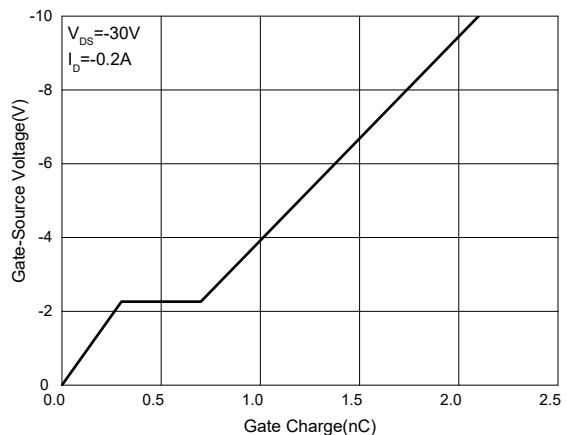


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

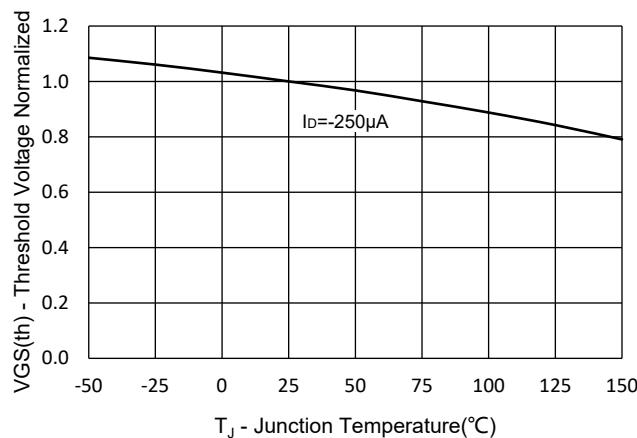


Fig.8 - Normalized On Resistance Characteristics

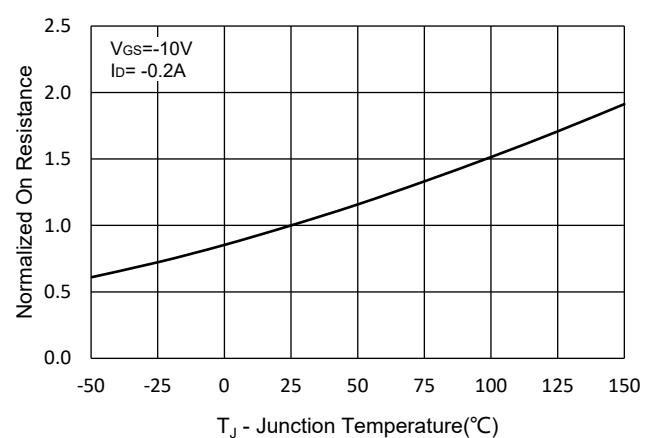


Fig.9 - I_S - V_{SD}

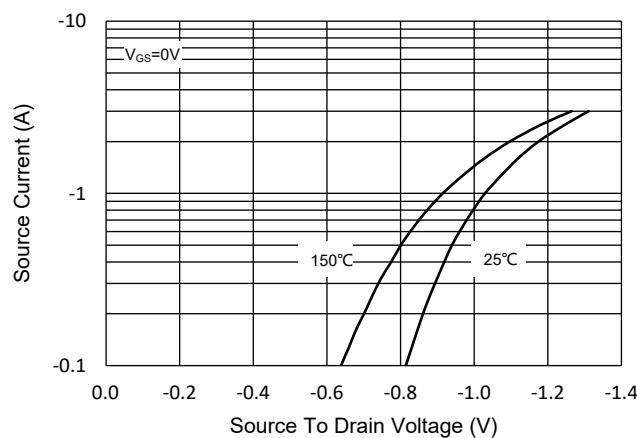


Fig.10 - Drain Current

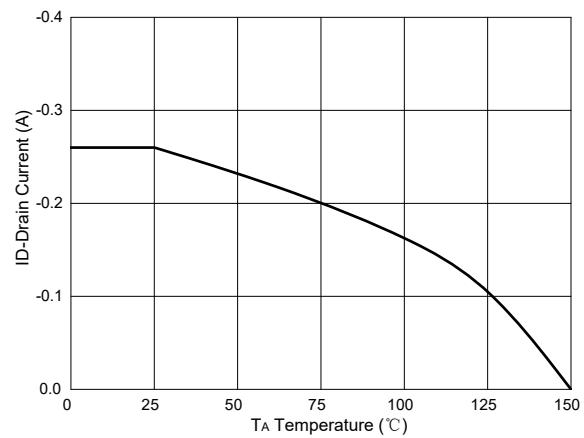
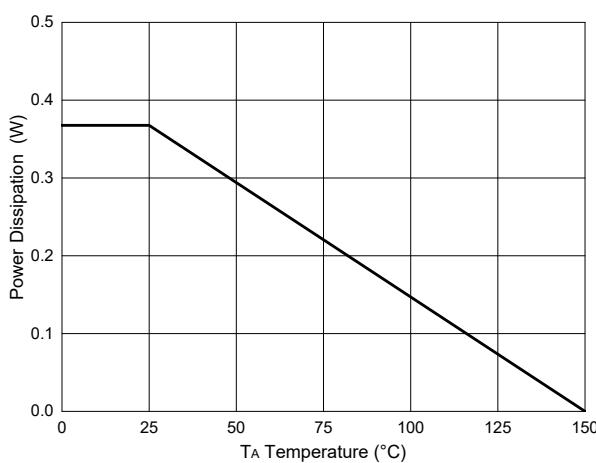


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

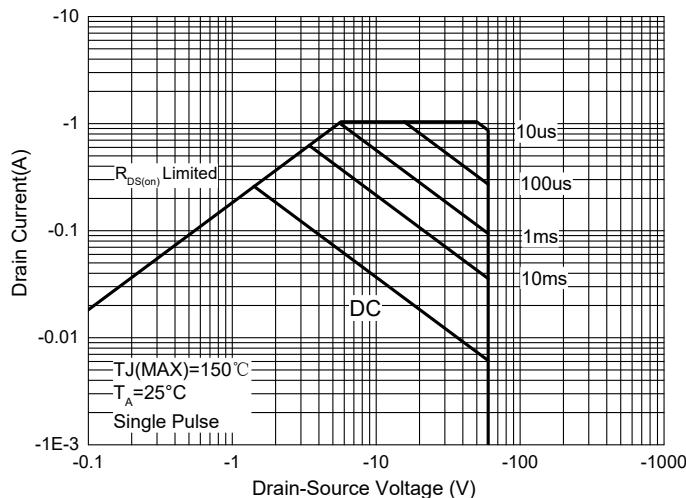
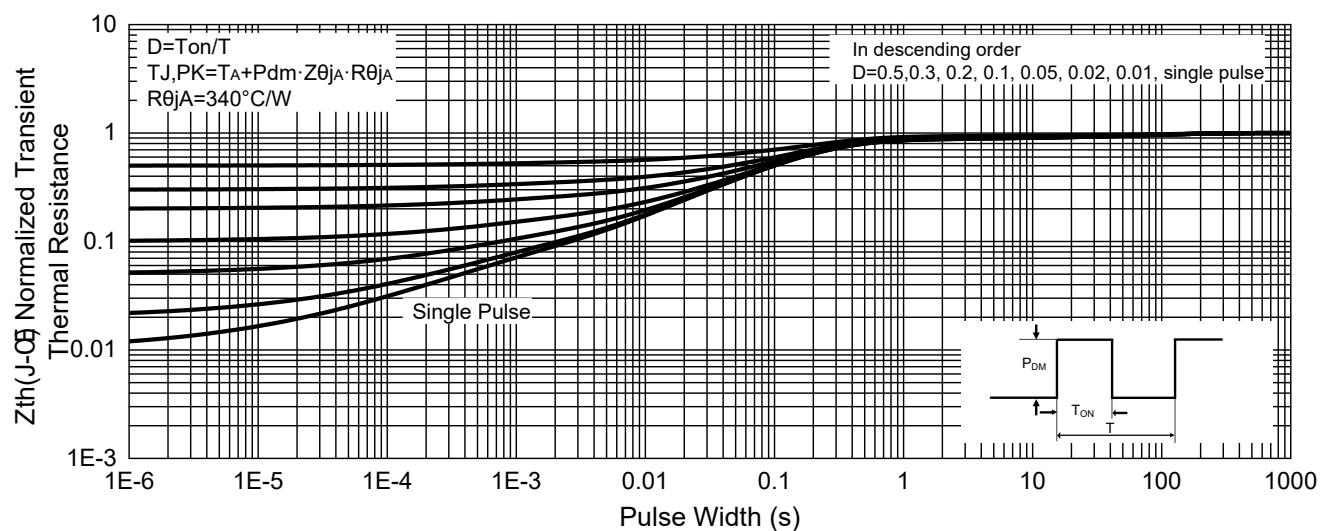


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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